

RoHS Compliant Product
A suffix of "-C" specifies halogen free

DESCRIPTION

The SSQF08N20-C is the highest performance N-ch MOSFETs with extreme high cell density, which provide excellent $R_{DS(ON)}$ and gate charge for most of the synchronous buck converter applications.

The SSQF08N20-C meet the RoHS and Green Product requirement with full function reliability approved.

FEATURES

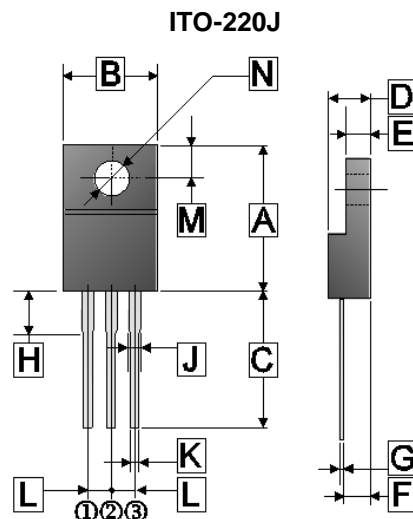
- High Speed Power Switching
- Super Low Gate Charge
- Green Device Available

MARKING

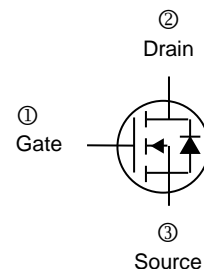


ORDER INFORMATION

Part Number	Type
SSQF08N20-C	Lead (Pb)-free and Halogen-free



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	14.8	15.2	H	2.2 REF.	
B	9.96	10.36	J	0.9 REF.	
C	13.20 REF.		K	0.5	0.75
D	4.35	4.65	L	2.54 REF.	
E	2.85	3.15	M	2.70 REF.	
F	2.60	2.80	N	ϕ 3.5 REF.	
G	0.50	0.75			



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V_{DS}	200	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ¹ @ $V_{GS}=10\text{V}$	I_D	$T_C=25^\circ\text{C}$	8
		$T_C=100^\circ\text{C}$	5
Pulsed Drain Current ⁴	I_{DM}	38	A
Power Dissipation ³	P_D	$T_C=25^\circ\text{C}$	32
		$T_A=25^\circ\text{C}$	2
Operating Junction & Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ\text{C}$
Thermal Resistance Ratings			
Thermal Resistance Junction-Ambient ¹	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
Thermal Resistance Junction-Ambient ²		110	
Thermal Resistance Junction-Case ¹	$R_{\theta JC}$	3.9	

ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$ unless otherwise specified)

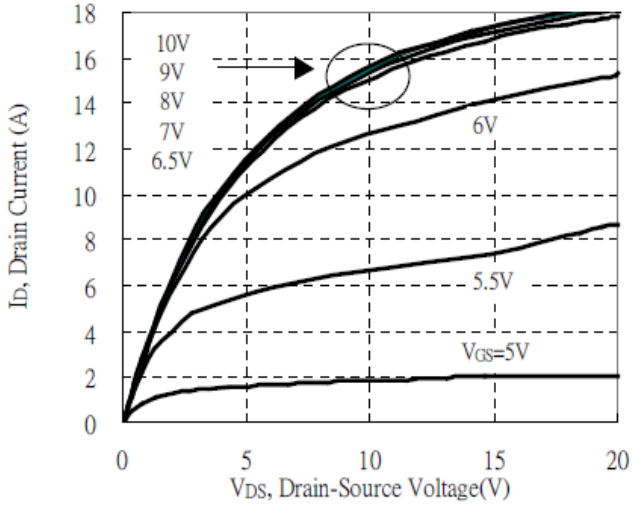
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	200	-	-	V	$V_{GS}=0V, I_D=250\mu A$	
Gate Threshold Voltage	$V_{GS(th)}$	2	-	4	V	$V_{DS}=V_{GS}, I_D=250\mu A$	
Forward Transconductance	g_{fs}	-	5.3	-	S	$V_{DS}=15V, I_D=5A$	
Gate-Source Leakage Current	I_{GSS}	-	-	± 100	nA	$V_{GS}=\pm 20V$	
Drain-Source Leakage Current	$T_J=25^\circ\text{C}$	I_{DSS}	-	-	1	μA	$V_{DS}=160V, V_{GS}=0V$
	$T_J=55^\circ\text{C}$		-	-	5		$V_{DS}=160V, V_{GS}=0V$
Static Drain-Source On-Resistance ²	$R_{DS(ON)}$	-	300	380	m Ω	$V_{GS}=10V, I_D=4A$	
		-	320	450		$V_{GS}=5.5V, I_D=3.5A$	
Total Gate Charge	Q_g	-	10.6	-	nC	$I_D=3A$ $V_{DS}=160V$ $V_{GS}=10V$	
Gate-Source Charge	Q_{gs}	-	2.3	-			
Gate-Drain Change	Q_{gd}	-	3.9	-			
Turn-on Delay Time	$T_{d(on)}$	-	8.8	-	nS	$V_{DS}=100V$ $I_D=3A$ $V_{GS}=10V$ $R_G=25\Omega$	
Rise Time	T_r	-	16.8	-			
Turn-off Delay Time	$T_{d(off)}$	-	21.2	-			
Fall Time	T_f	-	19.6	-			
Input Capacitance	C_{iss}	-	395	-	pF	$V_{GS}=0V$ $V_{DS}=25V$ $f=1\text{MHz}$	
Output Capacitance	C_{oss}	-	47	-			
Reverse Transfer Capacitance	C_{rss}	-	23	-			
Source-Drain Diode							
Diode Forward Voltage ²	V_{SD}	-	-	1.2	V	$I_S=1A, V_{GS}=0V$	
Continuous Source Current ¹	I_S	-	-	8	A	$V_{DS}=V_{GS}=0V, \text{Force Current}$	
Pulsed Source Current ⁴	I_{SM}	-	-	38	A		
Reverse Recovery Time	t_{rr}	-	50	-	nS	$I_F=3A, dI/dt=100A/\mu s,$	
Reverse Recovery Charge	Q_{rr}	-	86	-	nC	$T_J=25^\circ\text{C}$	

Notes:

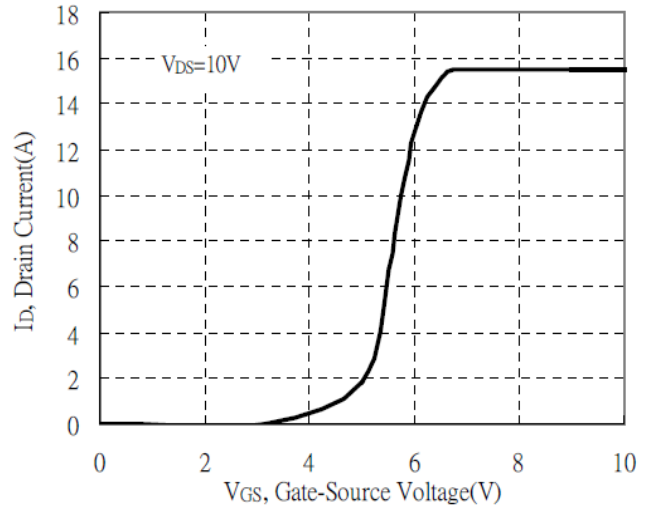
1. The data tested by surface mounted on a 1 inch² FR-4 board with 20Z copper.
2. The data tested by pulsed pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
3. The power dissipation is limited by 150 $^\circ\text{C}$ junction temperature.
4. Pulse width limited by maximum junction temperature, pulse width $\leq 10\mu s$, duty cycle $\leq 2\%$

TYPICAL CHARACTERISTIC

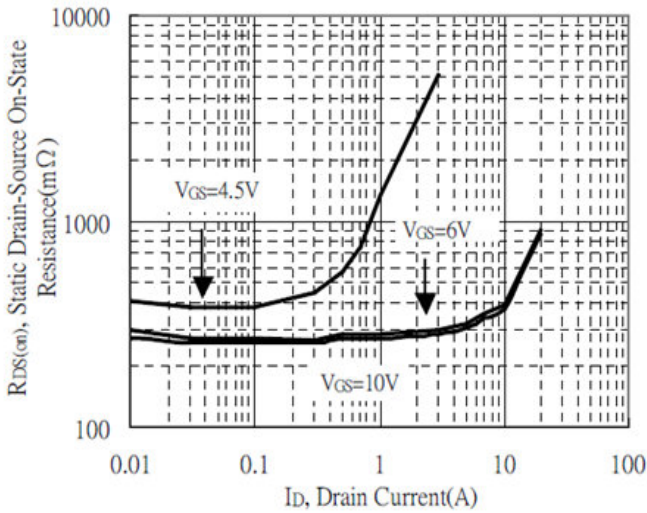
Typical Output Characteristics



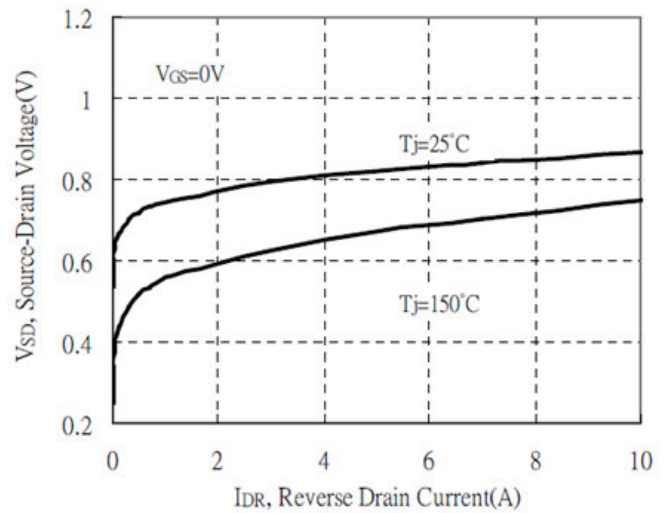
Typical Transfer Characteristics



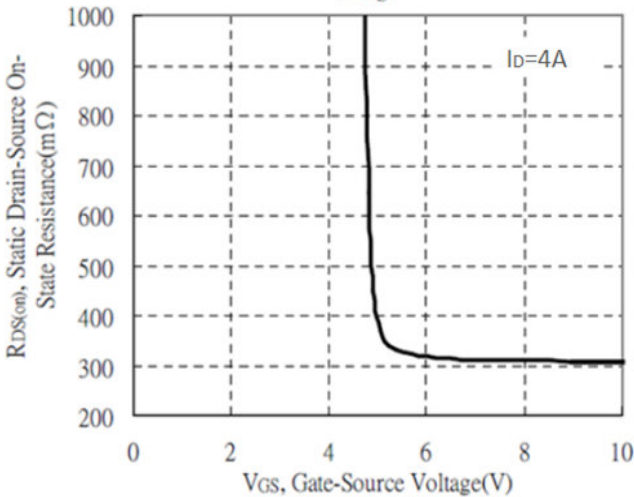
Static Drain-Source On-State resistance vs Drain Current



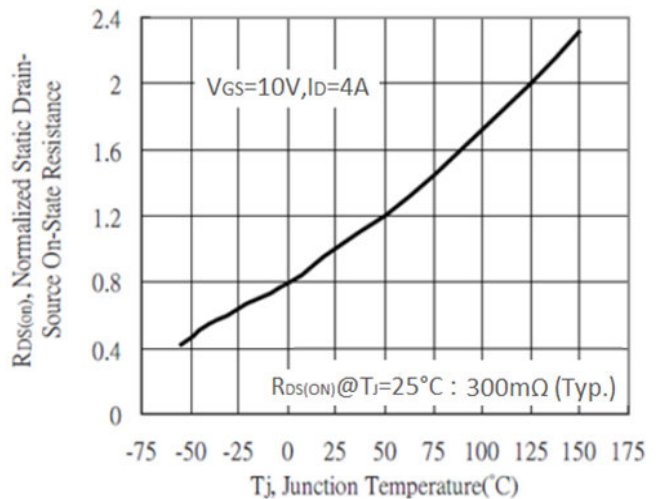
Reverse Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

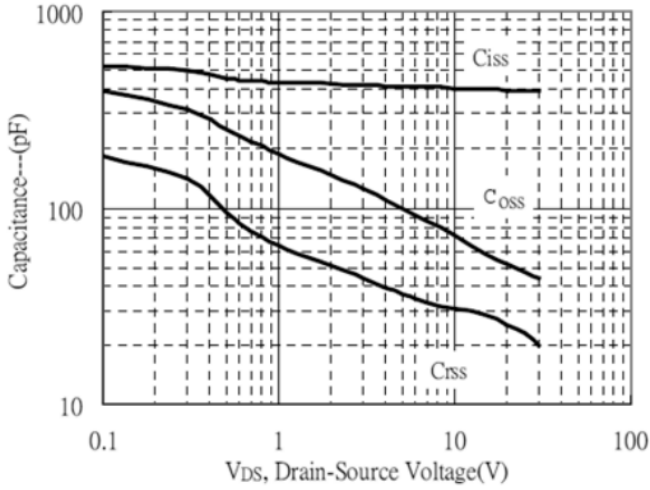


Drain-Source On-State Resistance vs Junction Temperature

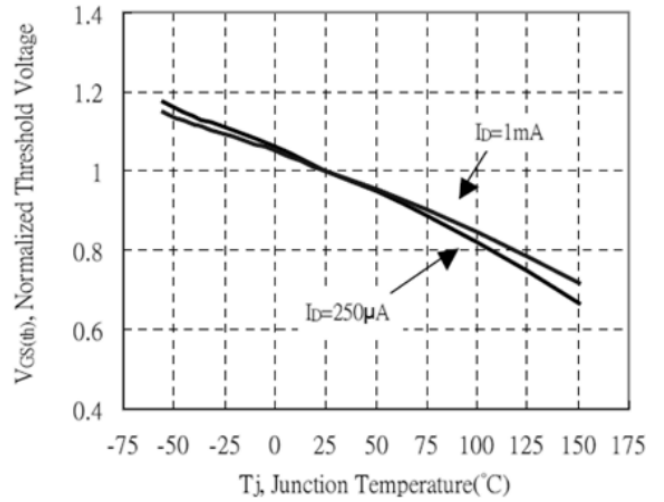


TYPICAL CHARACTERISTIC

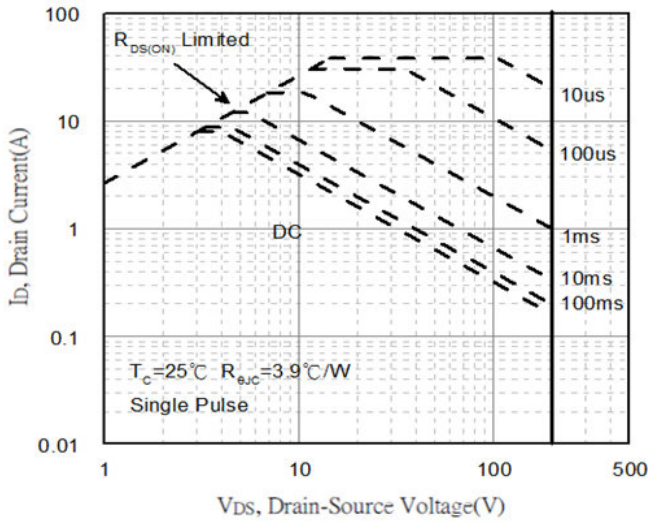
Capacitance vs Drain-to-Source Voltage



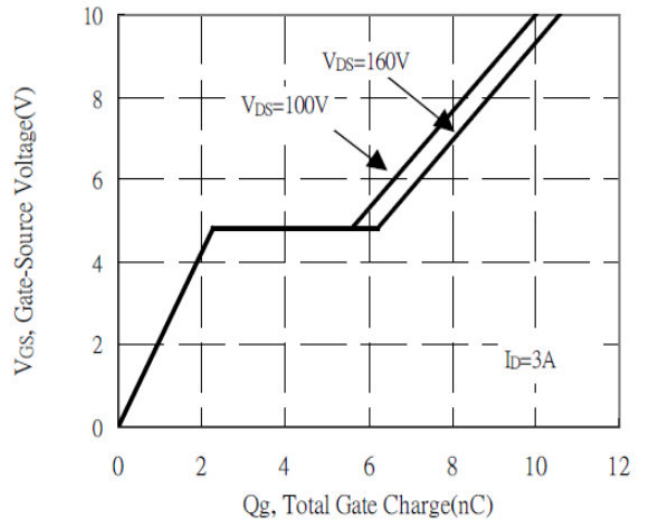
Threshold Voltage vs Junction Temperature



Maximum Safe Operating Area



Gate Charge Characteristics



Transient Thermal Response Curves

